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Renesas Electronics website: http://www.renesas.com

April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## **BIPOLAR ANALOG INTEGRATED CIRCUITS**

# $\mu$ PC2709TB

# 5 V, SUPER MINIMOLD SILICON MMIC MEDIUM OUTPUT POWER AMPLIFIER

#### DESCRIPTION

The  $\mu$ PC2709TB is a silicon monolithic integrated circuits designed as 1st IF amplifier for DBS tuners. This IC is packaged in super minimold package which is smaller than conventional minimold.

The  $\mu$ PC2709TB has compatible pin connections and performance to  $\mu$ PC2709T of conventional minimold version. So, in the case of reducing your system size,  $\mu$ PC2709TB is suitable to replace from  $\mu$ PC2709T.

These IC is manufactured using NEC's 20 GHz fτ NESAT™III silicon bipolar process. This process uses silicon nitride passivation film and gold electrodes. These materials can protect chip surface from external pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

#### **FEATURES**

High-density surface mounting: 6-pin super minimold package (2.0 x 1.25 x 0.9 mm)

• Wideband response : fu = 2.3 GHz TYP. @3 dB bandwidth

Medium output power
 Po (sat) = +11.5 dBm@f = 1 GHz with external inductor

Supply voltage : Vcc = 4.5 to 5.5 V

• Power gain :  $G_P = 23 \text{ dB TYP.} @f = 1 \text{ GHz}$ 

• Port impedance : input/output 50  $\Omega$ 

#### **APPLICATIONS**

· 1st IF amplifiers in DBS converters

· RF stage buffer in DBS tuners, etc.

#### **ORDERING INFORMATION**

Part Number	Package	Marking	Supplying Form
μPC2709TB-E3	6-pin super minimold	C1E	Embossed tape 8 mm wide. 1, 2, 3 pins face the perforation side of the tape. Qty 3 kpcs/reel.

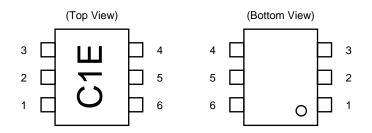
**Remark** To order evaluation samples, please contact your local NEC sales office (Part number for sample order:  $\mu$ PC2709TB).

#### Caution Electro-static sensitive devices

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### **PIN CONNECTIONS**



Pin No.	Pin Name		
1	INPUT		
2	GND		
3	GND		
4	OUTPUT		
5	GND		
6	Vcc		

## ★ PRODUCT LINE-UP OF 5 V-BIAS SILICON MMIC MEDIUM OUTPUT POWER AMPLIFIER (TA = +25°C, Vcc = Vout = 5.0 V, Zs = ZL = 50 $\Omega$ )

Part No.	fu (GHz)	Po (sat) (dBm)	G <sub>P</sub> (dB)	NF (dB)	Icc (mA)	Package	Marking
μPC2708T	2.0	+10.0	15	6.5	26	6-pin minimold	C1D
μPC2708TB	2.9	+10.0	15	@f = 1 GHz	20	6-pin super minimold	CID
μPC2709T	2.3	+11.5	23	5	25	6-pin minimold	C1E
μPC2709TB	2.3	+11.5	23	@f = 1 GHz	25	6-pin super minimold	CIE
μPC2710T	1.0	+13.5	33	3.5	22	6-pin minimold	C1F
μPC2710TB	1.0	+13.5	33	@f = 0.5 GHz	22	6-pin super minimold	CIF
μPC2776T	2.7	+8.5	23	6.0	25	6-pin minimold	C2L
μPC2776TB	2.7	C.0+	23	@f = 1 GHz	∠5	6-pin super minimold	C2L

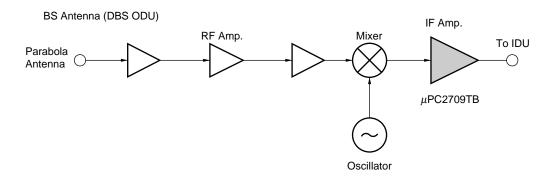
**Remark** Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

Caution The package size distinguishes between minimold and super minimold.

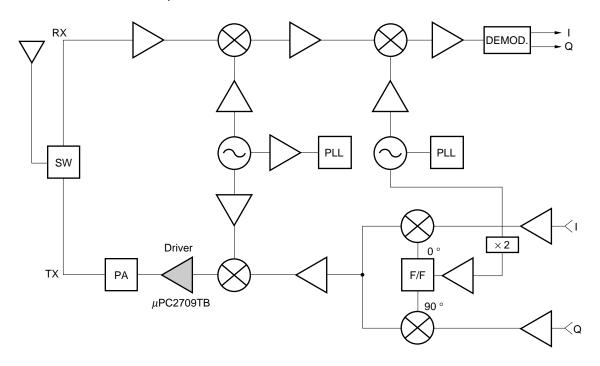


## SYSTEM APPLICATION EXAMPLE

## **EXAMPLE OF DBS CONVERTERS**



## EXAMPLE OF 900 MHz BAND, 1.5 GHz BAND DIGITAL CELLULAR TELEPHONE



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## PIN EXPLANATION

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V) <sup>Note</sup>	Function and Applications	Internal Equivalent Circuit
1	INPUT	-	1.05	Signal input pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band.  A multi-feedback circuit is designed to cancel the deviations of hee and resistance.  This pin must be coupled to signal source with capacitor for DC cut.	© Vcc
4	OUTPUT	Voltage as same as Vcc through external inductor	_	Signal output pin. The inductor must be attached between Vcc and output pins to supply current to the internal output transistors.	@ OUT
6	Vcc	4.5 to 5.5	-	Power supply pin, which biases the internal input transistor. This pin should be externally equipped with bypass capacitor to minimize its impedance.	3 Q+5 GND GND
2 3 5	GND	0	-	Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible.  All the ground pins must be connected together with wide ground pattern to decrease impedance defference.	

**Note** Pin voltage is measured at Vcc = 5.0 V



## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	Vcc	T <sub>A</sub> = +25°C, Pin 4 and 6	6	V
Total Circuit Current	Icc	T <sub>A</sub> = +25°C	60	mA
Power Dissipation	P <sub>D</sub>	Mounted on double copper clad $50 \times 50 \times 1.6$ mm epoxy glass PWB (T <sub>A</sub> = +85°C)	270	mW
Operating Ambient Temperature	TA		-40 to +85	°C
Storage Temperature	Tstg		-55 to +150	°C
Input Power	Pin	T <sub>A</sub> = +25°C	+10	dBm

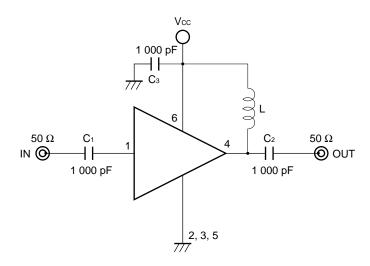
#### RECOMMENDED OPERATING RANGE

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Remark
Supply Voltage	Vcc	4.5	5.0	5.5	٧	The same voltage should be applied to pin 4 and 6.
Operating Ambient Temperature	TA	-40	+25	+85	°C	

## ELECTRICAL CHARACTERISTICS (TA = +25°C, Vcc = Vout = 5.0 V, Zs = ZL = 50 $\Omega$ )

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	Icc	No input signal	19	25	32	mA
Power Gain	G₽	f = 1 GHz	21.0	23.0	26.5	dB
Saturated Output Power	Po (sat)	f = 1 GHz, P <sub>in</sub> = 0 dBm	+9.0	+11.5	İ	dBm
Noise Figure	NF	f = 1 GHz	-	5.0	6.5	dB
Upper Limit Operating Frequency	fu	3 dB down below flat gain at f = 0.1 GHz	2.0	2.3	İ	GHz
Isolation	ISL	f = 1 GHz	26	31	-	dB
Input Return Loss	RLin	f = 1 GHz	7	10	İ	dB
Output Return Loss	RLout	f = 1 GHz	7	10	_	dB
Gain Flatness	ΔGp	f = 0.1 to 1.8 GHz	-	±1.0	-	dB

#### **TEST CIRCUIT**



## COMPONENTS OF TEST CIRCUIT FOR MEASURING ELECTRICAL CHARACTERISTICS EXAMPLE OF ACTURAL APPLICATION COMPONENTS

	Туре	Value
C <sub>1</sub> to C <sub>2</sub>	Bias Tee	1 000 pF
Сз	Capacitor	1 000 pF
L	Bias Tee	1 000 nH

	Туре	Value	Operating Frequency
C <sub>1</sub> to C <sub>3</sub>	Chip capacitor	1 000 pF	100 MHz or higher
L	Chip inductor	300 nH	10 MHz or higher
		100 nH	100 MHz or higher
		10 nH	1.0 GHz or higher

#### INDUCTOR FOR THE OUTPUT PIN

The internal output transistor of this IC consumes 20 mA, to output medium power. To supply current for output transistor, connect an inductor between the Vcc pin (pin 6) and output pin (pin 4). Select large value inductance, as listed above.

The inductor has both DC and AC effects. In terms of DC, the inductor biases the output transistor with minimum voltage drop to output enable high level. In terms of AC, the inductor make output-port impedance higher to get enough gain. In this case, large inductance and Q is suitable.

#### CAPACITORS FOR THE Vcc, INPUT, AND OUTPUT PINS

Capacitors of 1 000 pF are recommendable as the bypass capacitor for the Vcc pin and the coupling capacitors for the input and output pins.

The bypass capacitor connected to the Vcc pin is used to minimize ground impedance of Vcc pin. So, stable bias can be supplied against Vcc fluctuation.

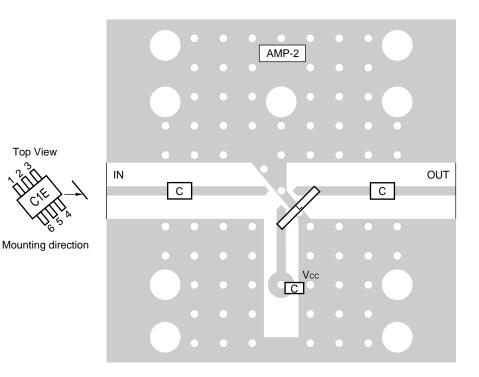
The coupling capacitors, connected to the input and output pins, are used to cut the DC and minimize RF serial impedance. Their capacitance are therefore selected as lower impedance against a 50  $\Omega$  load. The capacitors thus perform as high pass filters, suppressing low frequencies to DC.

To obtain a flat gain from 100 MHz upwards, 1 000 pF capacitors are used in the test circuit. In the case of under 10 MHz operation, increase the value of coupling capacitor such as 10 000 pF. Because the coupling capacitors are determined by equation,  $C = 1/(2 \pi Rfc)$ .

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#### ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



#### **COMPONENT LIST**

	Value
С	1 000 pF
L	300 nH

#### **Notes**

1.  $30 \times 30 \times 0.4$  mm double sided copper clad polyimide board.

2. Back side: GND pattern

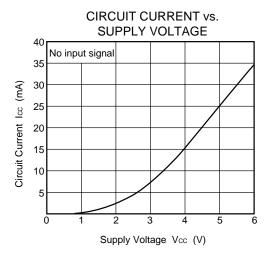
3. Solder plated on pattern

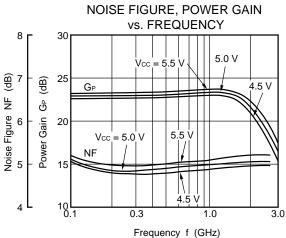
4. O : Through holes

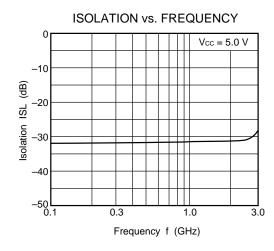
For more information on the use of this IC, refer to the following application note:

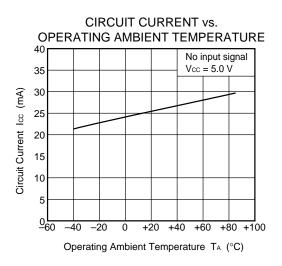
USAGE AND APPLICATION OF SILICON MEDIUM-POWER HIGH-FREQUENCY AMPLIFIER MMIC (P12152E).

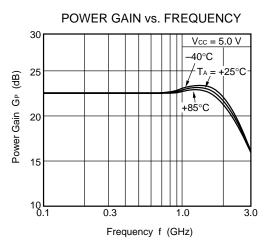
#### TYPICAL CHARACTERISTICS (Unless otherwise specified, TA = +25°C)

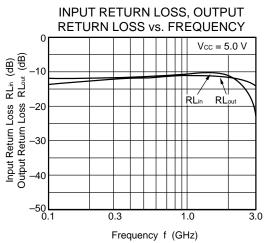


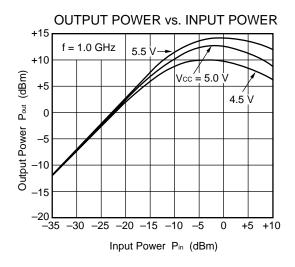


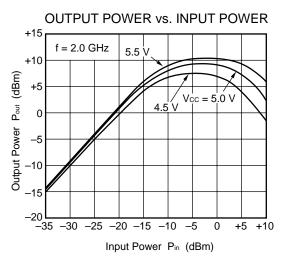


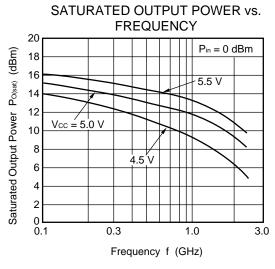




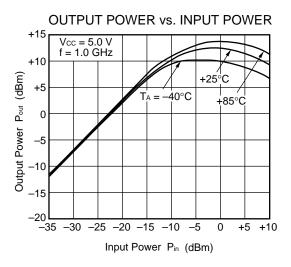


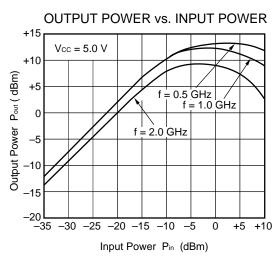


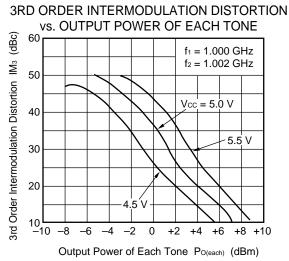






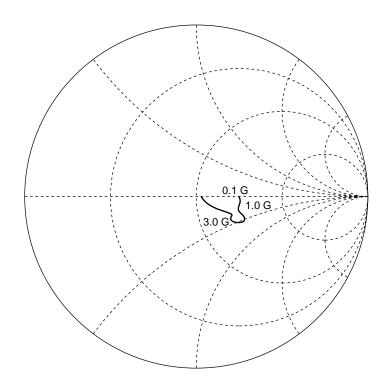




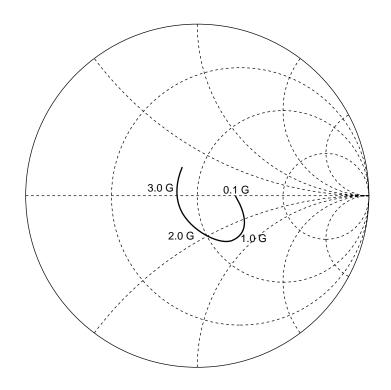


## S-PARAMETERS (TA = +25°C, Vcc = Vout = 5.0 V)

## S<sub>11</sub>-FREQUENCY



## S<sub>22</sub>-FREQUENCY





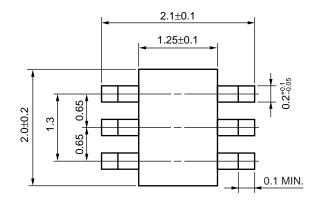
## TYPICAL S-PARAMETER VALUES ( $T_A = +25$ °C)

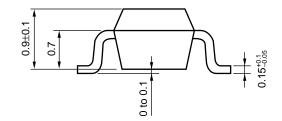
Vcc = Vout = 5.0 V, Icc = 26 mA

Frequency	S	S <sub>11</sub>	5	S <sub>21</sub>	S	12	S	S22	K
MHz	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	
400,0000	0.007	0.0	40.000	4.5	0.007	4.0	0.400	0.0	4.07
100.0000	0.227	0.2	13.698	<b>-4.5</b>	0.027	-1.0	0.196	0.9	1.37
200.0000	0.239	1.0	13.724	-9.6	0.027	3.1	0.207	2.2	1.36
300.0000	0.245	2.9	13.830	-14.5	0.026	4.7	0.212	4.1	1.38
400.0000	0.244	2.5	13.998	-19.9	0.027	7.8	0.223	3.4	1.32
500.0000	0.243	1.5	14.109	-25.0	0.026	9.8	0.234	2.1	1.33
600.0000	0.247	-1.5	14.246	-30.4	0.027	11.9	0.252	-0.4	1.26
700.0000	0.265	-3.2	14.538	-35.5	0.028	13.6	0.270	-2.3	1.20
800.0000	0.284	-3.6	14.703	-41.3	0.028	14.9	0.287	-4.6	1.15
900.0000	0.301	-3.3	15.051	-47.0	0.028	17.2	0.298	<b>-7.4</b>	1.10
1000.0000	0.305	-2.4	15.331	<b>-</b> 53.5	0.029	18.8	0.309	-11.9	1.05
1100.0000	0.299	-3.2	15.605	-60.0	0.029	20.9	0.322	-17.1	1.04
1200.0000	0.300	-6.3	15.773	-66.7	0.029	22.5	0.336	-21.5	1.01
1300.0000	0.314	-10.3	16.152	-74.0	0.030	23.8	0.353	-24.8	0.95
1400.0000	0.328	-14.4	16.282	-81.0	0.030	26.1	0.353	-28.8	0.93
1500.0000	0.354	-17.3	16.337	-89.3	0.032	25.6	0.368	-35.5	0.86
1600.0000	0.359	-19.5	16.370	-96.5	0.031	26.8	0.370	-41.8	0.86
1700.0000	0.373	-22.1	16.256	-104.5	0.033	28.0	0.382	-46.9	0.81
1800.0000	0.371	-26.8	15.977	-112.7	0.032	29.3	0.381	-52.8	0.83
1900.0000	0.379	-31.1	15.529	-120.5	0.033	31.3	0.378	-57.8	0.83
2000.0000	0.386	-36.0	15.307	-128.1	0.034	31.0	0.373	-64.1	0.82
2100.0000	0.387	-39.5	14.745	-135.9	0.033	32.2	0.366	-70.8	0.85
2200.0000	0.374	-43.8	14.212	-143.7	0.033	30.5	0.363	-78.1	0.90
2300.0000	0.360	-48.7	13.633	-151.3	0.033	33.9	0.353	-83.0	0.94
2400.0000	0.339	-55.4	12.846	-158.7	0.032	35.5	0.331	-90.0	1.06
2500.0000	0.338	-62.0	11.990	-165.5	0.033	38.0	0.318	-95.6	1.11
2600.0000	0.334	-66.0	11.265	-172.1	0.033	39.1	0.304	-102.5	1.20
2700.0000	0.330	-69.0	10.560	-177.8	0.033	40.8	0.295	-108.3	1.25
2800.0000	0.311	-69.9	9.942	176.2	0.033	43.5	0.282	-113.7	1.36
2900.0000	0.291	-72.5	9.432	171.3	0.035	44.9	0.267	-118.6	1.40
3000.0000	0.258	-76.5	8.818	166.5	0.035	47.4	0.246	-125.1	1.55
3100.0000	0.240	-80.6	8.353	161.9	0.035	53.4	0.225	-131.2	1.64

## **★ PACKAGE DIMENSIONS**

## 6-PIN SUPER MINIMOLD (UNIT: mm)







#### NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation). All the ground pins must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to the Vcc pin.
- (4) The inductor (L) must be attached between Vcc and output pins. The inductance value should be determined in accordance with desired frequency.
- (5) The DC cut capacitor must be attached to input and output pin.

#### RECOMMENDED SOLDERING CONDITIONS

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235°C or below Time: 30 seconds or less (at 210°C) Count: 3, Exposure limit: None <sup>Note</sup>	IR35-00-3
VPS	Package peak temperature: 215°C or below Time: 40 seconds or less (at 200°C) Count: 3, Exposure limit: None <sup>Note</sup>	VP15-00-3
Wave Soldering	Soldering bath temperature: 260°C or below Time: 10 seconds or less Count: 1, Exposure limit: None <sup>Note</sup>	WS60-00-1
Partial Heating	Pin temperature: 300°C Time: 3 seconds or less (per side of device) Exposure limit: None <sup>Note</sup>	-

Note After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document **SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL** (C10535E).

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  circuits, software and information in the design of customer's equipment shall be done under the full
  responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third
  parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
  agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
  risks of damage to property or injury (including death) to persons arising from defects in NEC
  semiconductor products, customers must incorporate sufficient safety measures in their design, such as
  redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
  - "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.
  - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
  - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
  - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

- (1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).

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